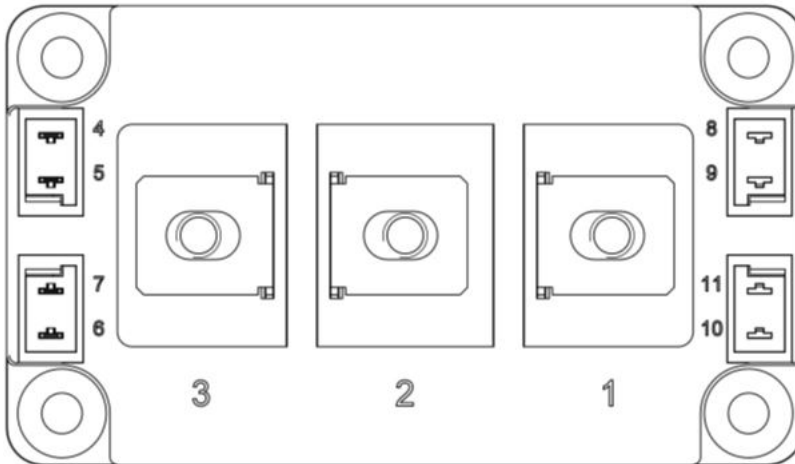
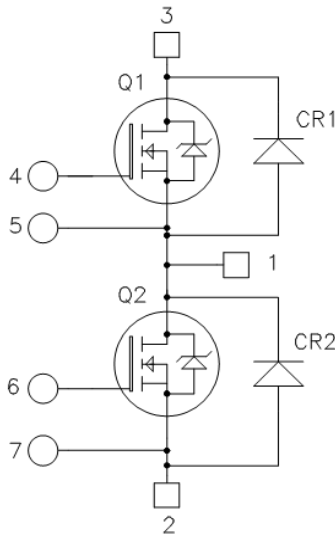


Phase Leg SiC Power Module

Product Overview

The MSCSM170AM039CD3AG device is a 1700 V/523 A phase leg silicon carbide (SiC) power module.



All ratings at $T_J = 25\text{ }^\circ\text{C}$, unless otherwise specified.

Caution: These devices are sensitive to electrostatic discharge. Proper handling procedures must be followed.

Features

The following are the key features of MSCSM170AM039CD3AG device:

- SiC Power MOSFET
 - Low $R_{DS(on)}$
 - High temperature performance
- SiC Schottky Diode
 - Zero reverse recovery
 - Zero forward recovery
 - Temperature Independent switching behavior
 - Positive temperature coefficient on VF
- Kelvin emitter for easy drive
- High level of integration
- M6 power connectors
- Aluminum Nitride (AlN) substrate for improved thermal performance

Benefits

The following are the benefits of MSCSM170AM039CD3AG device:

- High efficiency converter
- Stable temperature behavior
- Direct mounting to heatsink (isolated package)
- Low junction-to-case thermal resistance
- RoHS Compliant

Applications

The following are the applications of MSCSM170AM039CD3AG device:

- Welding converters
- Switched mode power supplies
- Uninterruptible power supplies
- EV motor and traction drive

1. Electrical Specifications

The following sections show the electrical specifications of the MSCSM170AM039CD3AG device.

1.1 SiC MOSFET Characteristics (Per SiC MOSFET)

The following table lists the absolute maximum ratings (per SiC MOSFET) of the MSCSM170AM039CD3AG device.

Table 1-1. Absolute Maximum Ratings

Symbol	Parameter	Maximum Ratings	Unit
V_{DSS}	Drain-Source voltage	1700	V
I_D	Continuous drain current	$T_C = 25\text{ }^\circ\text{C}$	523
		$T_C = 80\text{ }^\circ\text{C}$	416
I_{DM}	Pulsed drain current	1000	
V_{GS}	Gate-Source voltage	-10/23	V
$R_{DS(on)}$	Drain-Source ON resistance	5	m Ω
P_D	Power dissipation	$T_C = 25\text{ }^\circ\text{C}$	2400

The following table lists the electrical characteristics (per SiC MOSFET) of the MSCSM170AM039CD3AG device.

Table 1-2. Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit	
I_{DSS}	Zero gate voltage drain current	$V_{GS} = 0\text{ V}; V_{DS} = 1700\text{ V}$	—	90	900	μA	
$R_{DS(on)}$	Drain-Source on resistance	$V_{GS} = 20\text{ V}$ $I_D = 270\text{ A}$	$T_J = 25\text{ }^\circ\text{C}$	—	3.9	5	m Ω
			$T_J = 175\text{ }^\circ\text{C}$	—	6.8	—	
$V_{GS(th)}$	Gate threshold voltage	$V_{GS} = V_{DS}; I_D = 22.5\text{ mA}$	1.8	3.3	—	V	
I_{GSS}	Gate-Source leakage current	$V_{GS} = 20\text{ V}; V_{DS} = 0\text{ V}$	—	—	900	nA	

The following table lists the dynamic characteristics (per SiC MOSFET) of the MSCSM170AM039CD3AG device.

Table 1-3. Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit	
C_{iss}	Input capacitance	$V_{GS} = 0\text{ V}$	—	29.7	—	nF	
C_{oss}	Output capacitance	$V_{DS} = 1000\text{ V}$	—	1.3	—		
C_{rss}	Reverse transfer capacitance	$f = 1\text{ MHz}$	—	0.09	—		
Q_g	Total gate charge	$V_{GS} = -5\text{ V}/20\text{ V}$	—	1602	—	nC	
Q_{gs}	Gate-source charge	$V_{Bus} = 850\text{ V}$	—	441	—		
Q_{gd}	Gate-drain charge	$I_D = 270\text{ A}$	—	243	—		
$T_{d(on)}$	Turn-on delay time	$V_{GS} = -5\text{ V}/20\text{ V}$	—	75	—	ns	
T_r	Rise time	$V_{Bus} = 900\text{ V}$	—	75	—		
$T_{d(off)}$	Turn-off delay time	$I_D = 450\text{ A}$	—	153	—		
T_f	Fall time	$T_J = 150\text{ °C}$ $R_{GON} = 3.2\ \Omega$ $R_{GOFF} = 1.8\ \Omega$	—	56	—		
E_{on}	Turn-on energy	$V_{GS} = -5\text{ V}/20\text{ V}$	$T_J = 150\text{ °C}$	—	20.3	—	mJ
E_{off}	Turn-off energy	$V_{Bus} = 900\text{ V}$ $I_D = 450\text{ A}$ $R_{GON} = 3.2\ \Omega$ $R_{GOFF} = 1.8\ \Omega$	$T_J = 150\text{ °C}$	—	10.8	—	mJ
R_{Gint}	Internal gate resistance		—	0.65	—	Ω	
R_{thJC}	Junction-to-case thermal resistance		—	—	0.063	$^{\circ}\text{C}/\text{W}$	

The following table lists the body diode ratings and characteristics (per SiC MOSFET) of the MSCSM170AM039CD3AG device.

Table 1-4. Body Diode Ratings and Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
V_{SD}	Diode forward voltage	$V_{GS} = 0\text{ V}; I_{SD} = 270\text{ A}$	—	3.7	—	V
		$V_{GS} = -5\text{ V}; I_{SD} = 270\text{ A}$	—	3.9	—	
t_{rr}	Reverse recovery time	$I_{SD} = 270\text{ A}$	—	27	—	ns
Q_{rr}	Reverse recovery charge	$V_{GS} = -5\text{ V}$	—	5.9	—	μC
I_{rr}	Reverse recovery current	$V_R = 900\text{ V}$ $di_F/dt = 9000\text{ A}/\mu\text{s}$	—	414	—	A

1.2 SiC Schottky Diode Ratings and Characteristics (Per SiC Diode)

The following table lists the SiC Schottky diode ratings and characteristics of the MSCSM170AM039CD3AG device.

Table 1-5. SiC Schottky Diode Ratings and Characteristics (Per SiC Diode)

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit	
V_{RRM}	Peak repetitive reverse voltage	—	—	—	1700	V	
I_{RRM}	Reverse leakage current	$V_R = 1700\text{ V}$	$T_J = 25\text{ °C}$	—	70	1400	μA
			$T_J = 175\text{ °C}$	—	1050	—	
I_F	DC forward current	—	$T_C = 125\text{ °C}$	—	210	A	
V_F	Diode forward voltage	$I_F = 210\text{ A}$	$T_J = 25\text{ °C}$	—	1.5	1.8	V
			$T_J = 175\text{ °C}$	—	2.3	—	
Q_C	Total capacitive charge	$V_R = 900\text{ V}$	—	1610	—	nC	
C	Total capacitance	$f = 1\text{ MHz}, V_R = 600\text{ V}$	—	1169	—	pF	
		$f = 1\text{ MHz}, V_R = 900\text{ V}$	—	966	—		
R_{thJC}	Junction-to-case thermal resistance	—	—	—	0.09	$^{\circ}\text{C/W}$	

1.3 Thermal and Package Characteristics

The following table lists the package characteristics of the MSCSM170AM039CD3AG device.

Table 1-6. Thermal and Package Characteristics

Symbol	Characteristic	Min	Max	Unit		
V_{ISOL}	RMS isolation voltage, any terminal to case $t = 1\text{ min}$, 50 Hz/60 Hz	4000	—	V		
T_J	Operating junction temperature range	−40	175	$^{\circ}\text{C}$		
T_{JOP}	Recommended junction temperature under switching conditions	−40	$T_{Jmax} - 25$			
T_{STG}	Storage case temperature	−40	125			
T_C	Operating case temperature	−40	125			
Torque	Mounting torque	For terminals	M6		3	5
		To heatsink	M6	3	5	
Wt	Package weight	—	350	g		

1.4 Typical SiC MOSFET Performance Curve

The following figures show the SiC MOSFET performance curves of the MSCSM170AM039CD3AG device.

Figure 1-1. Maximum Thermal Impedance

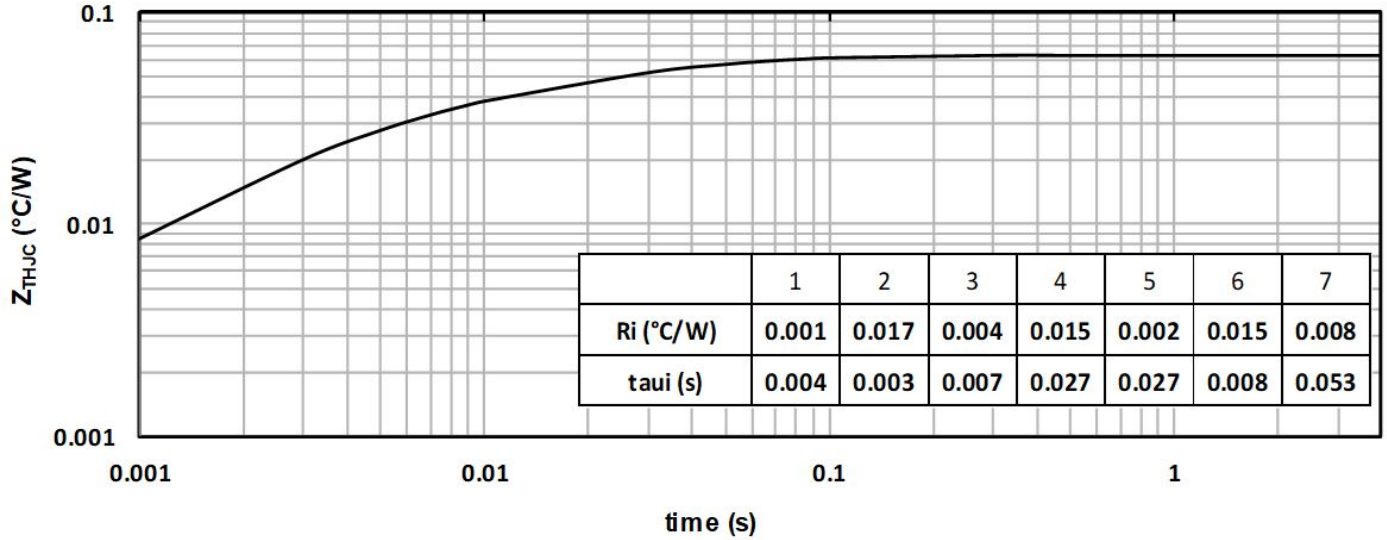


Figure 1-2. Output Characteristics, $T_J = 25^\circ\text{C}$

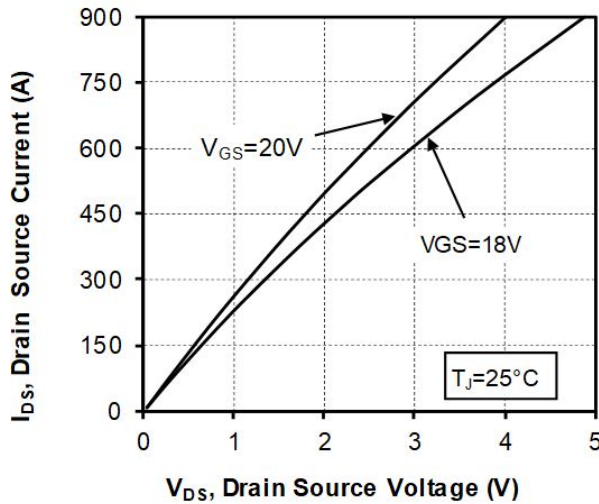


Figure 1-3. Output Characteristics, $T_J = 175^\circ\text{C}$

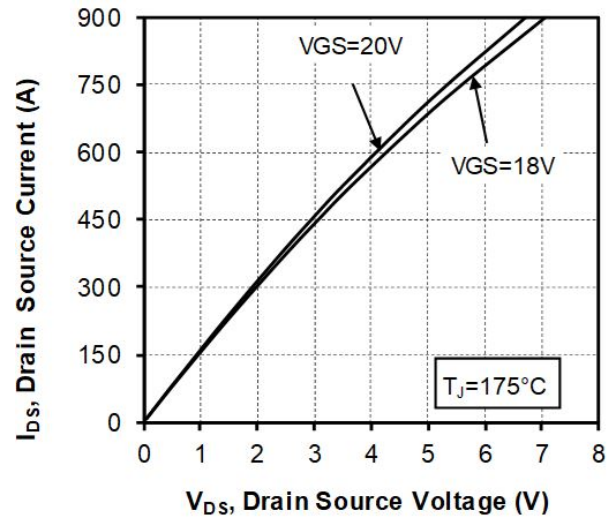


Figure 1-4. Normalized $R_{DS(on)}$ vs. Temperature

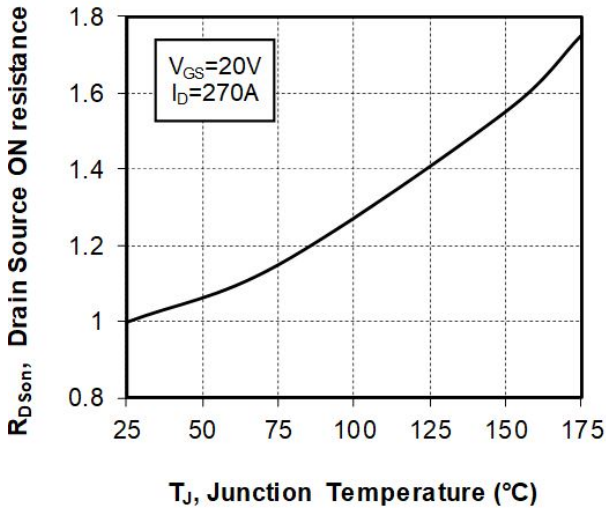


Figure 1-5. Transfer Characteristics

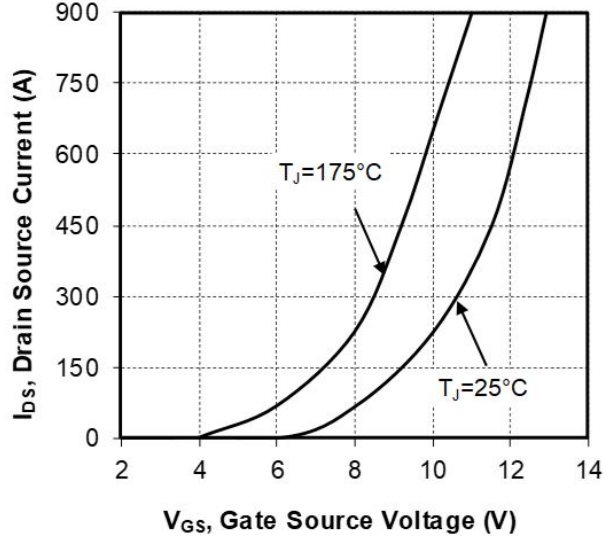


Figure 1-6. Switching Energy vs. R_g

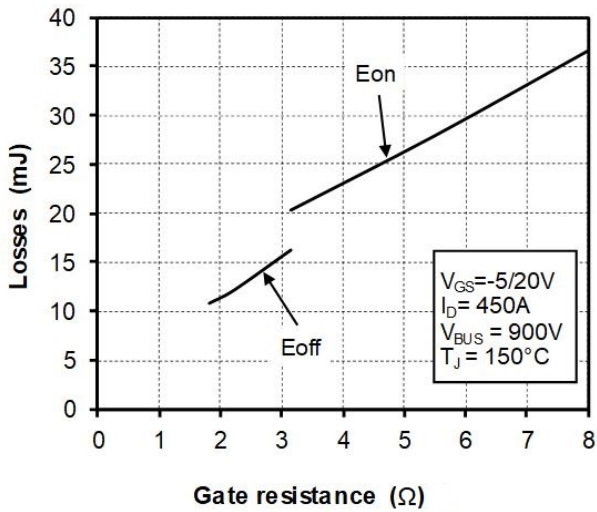


Figure 1-7. Switching Energy vs. Current

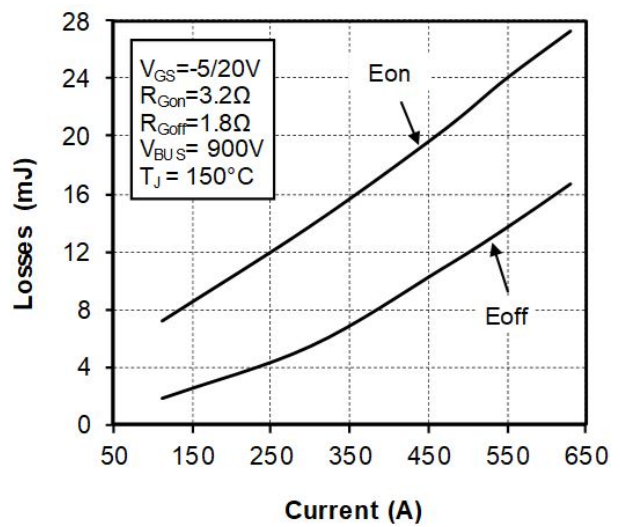


Figure 1-8. Capacitance vs. Drain Source Voltage

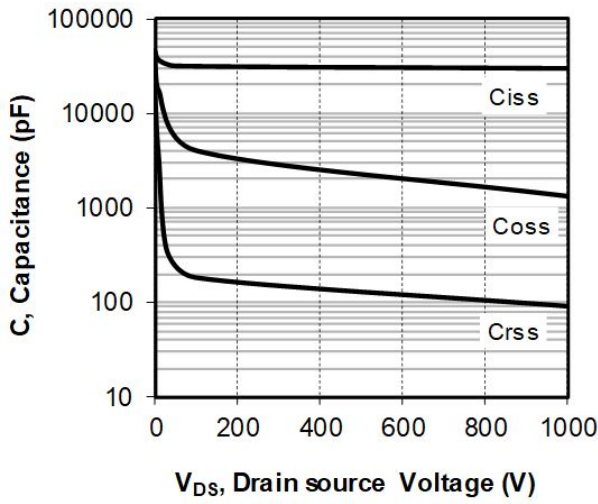


Figure 1-9. Gate Charge vs. Gate Source Voltage

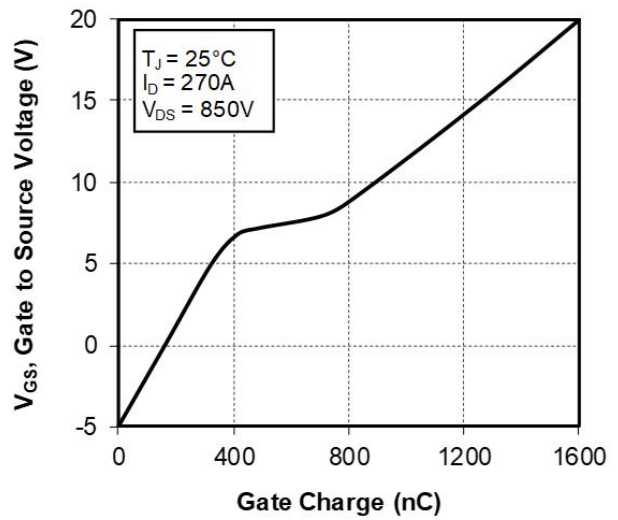


Figure 1-10. Body Diode Characteristics, $T_J = 25^\circ\text{C}$

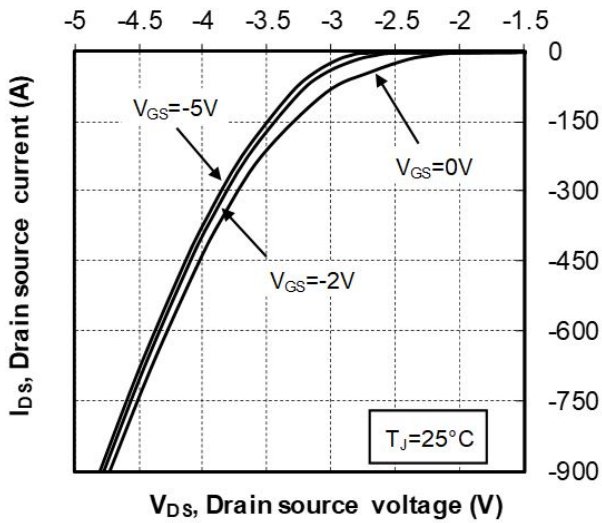


Figure 1-11. 3rd Quadrant Characteristics, $T_J = 25^\circ\text{C}$

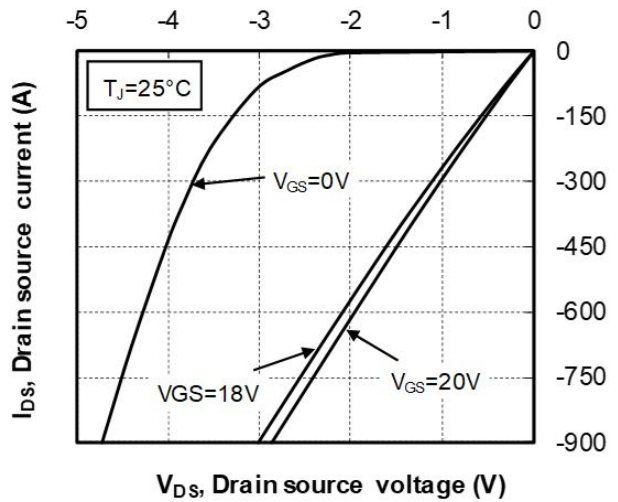


Figure 1-12. Body Diode Characteristics, $T_J = 175^\circ\text{C}$

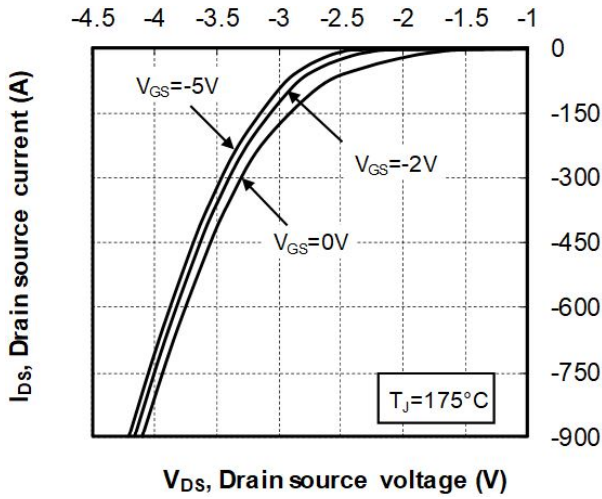


Figure 1-13. 3rd Quadrant Characteristics, $T_J = 175^\circ\text{C}$

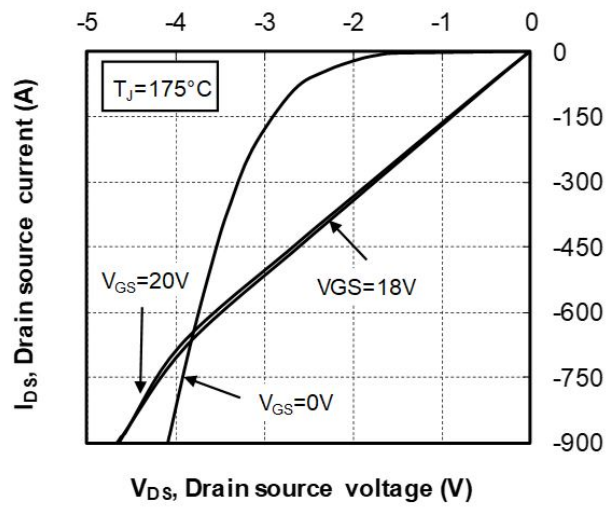
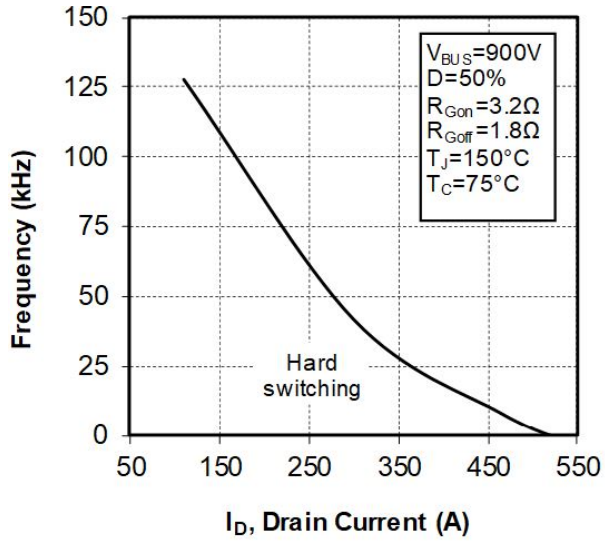


Figure 1-14. Operating Frequency vs. Drain Current



1.5 Typical SiC Diode Performance Curve

The following figures show the SiC diode performance curves of the MSCSM170AM039CD3AG device.

Figure 1-15. Maximum Thermal Impedance

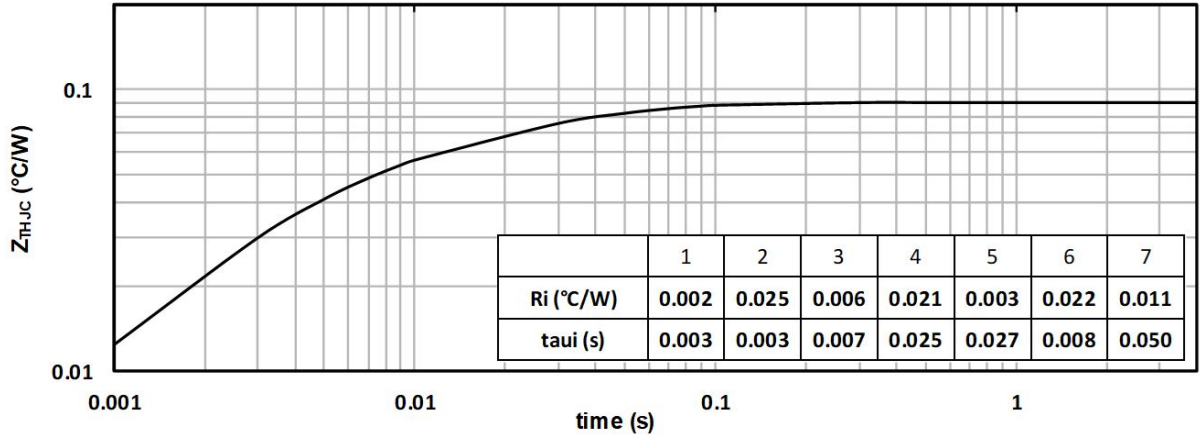


Figure 1-16. Forward Characteristics

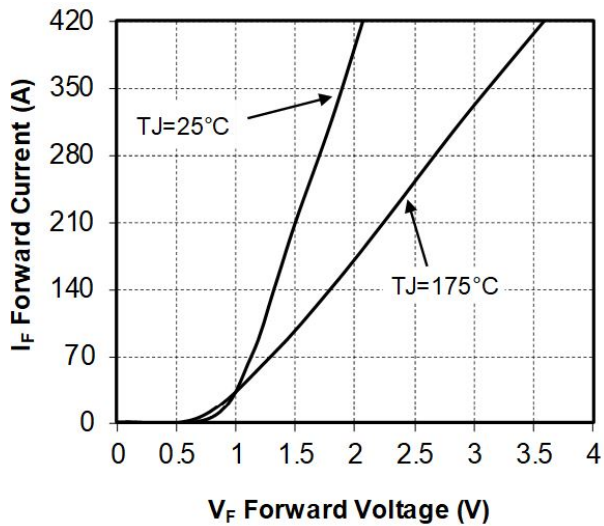
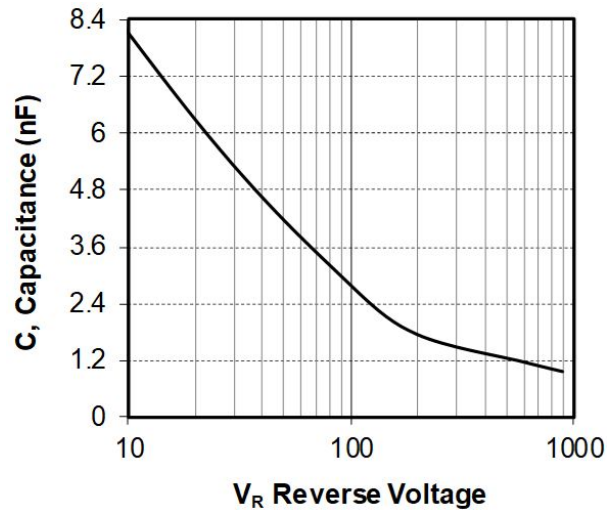


Figure 1-17. Capacitance vs. Reverse Voltage



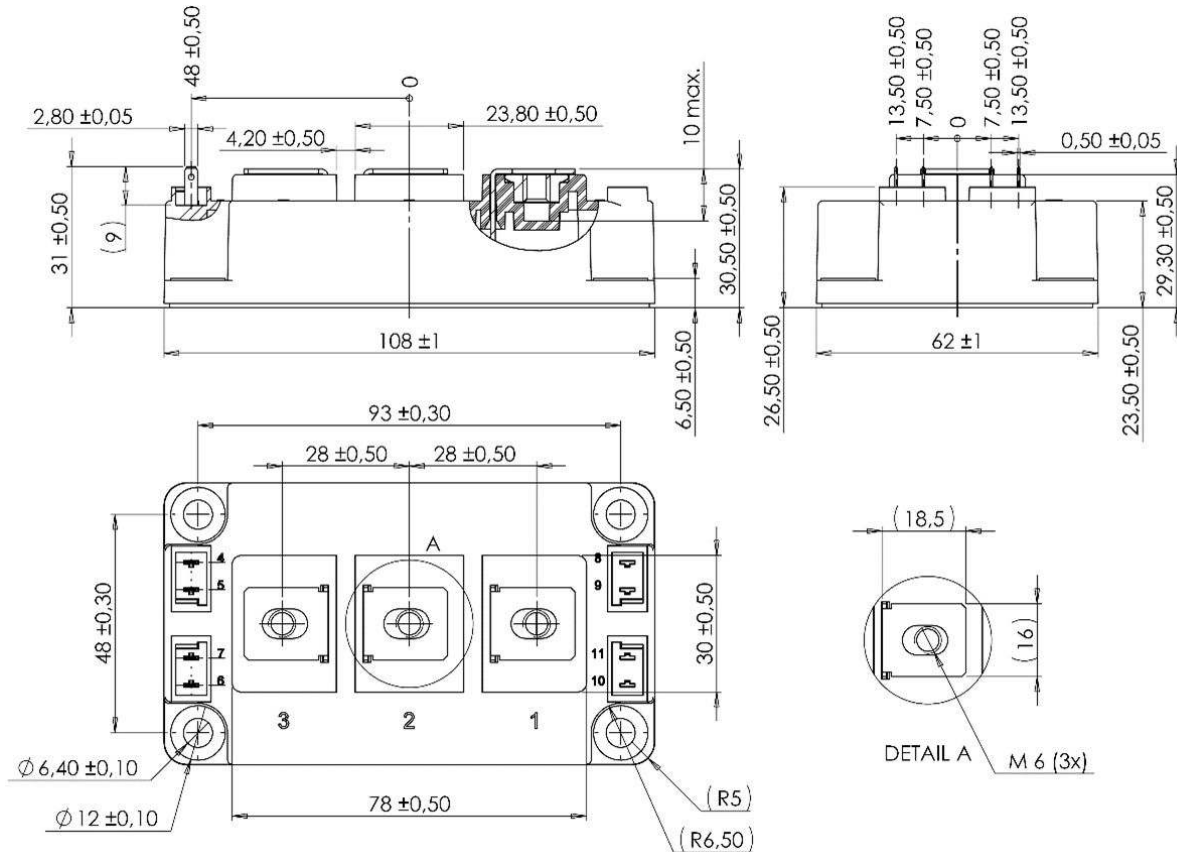
2. Package Specifications

The following section shows the package specification of the MSCSM170AM039CD3AG device.

2.1 Package Outline

The following figure shows the package outline drawing of the MSCSM170AM039CD3AG device. The dimensions in the following figure are in millimeters.

Figure 2-1. Package Outline Drawing



Note: See application note [1908—Mounting instructions for D3 and D4 power modules](#) for more information.

3. Revision History

Revision	Date	Description
A	04/2021	This is the first publication of this document.

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